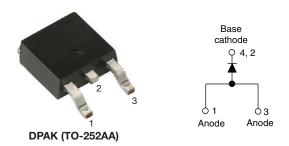
Vishay Semiconductors

High Performance Schottky Rectifier, 5.5 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)}	5.5 A			
V _R	100 V			
V _F at I _F	See Electrical table			
I _{RM}	4 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	6 mJ			
Circuit configuration	Single			
Package	DPAK (TO-252AA)			

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular DPAK outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-50WQ10FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN					
I _{F(AV)}	Rectangular waveform	5.5	A				
V _{RRM}		100	V				
I _{FSM}	t _p = 5 μs sine	330	А				
V _F	5 A _{pk} , T _J = 125 °C	0.63	V				
TJ	Range	-40 to +150	°C				

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-50WQ10FNHM3	UNITS		
Maximum DC reverse voltage	V _R	100	V		
Maximum working peak reverse voltage	V _{RWM}	100	v		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	$I_{F(AV)}$ 50 % duty cycle at T _C = 135 °C, rectangular waveform		5.5		
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	330	A	
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	110		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 40 mH		6.0	mJ	
Repetitive avalanche current	I _{AR}		It decaying linearly to zero in 1 μ s ency limited by T _J maximum V _A = 1.5 x V _R typical		А	

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FREE



VS-50WQ10FNHM3

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST COND	DITIONS	VALUES	UNITS	
		5 A	T _{.1} = 25 °C	0.77	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	1j=25 0	0.91		
See fig. 1	VFM (")	5 A	T.I = 125 °C	0.63		
		10 A	1j = 125 C	0.74		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = Rated V_{\rm B}$	1	mA	
See fig. 2	IRM \''	T _J = 125 °C	VR = haleu VR	4		
Threshold voltage	V _{F(TO)}	T ₁ =T ₁ maximum		0.47	V	
Forward slope resistance	r _t			21.46	mΩ	
Typical junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C 183 pl			pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0 nl			nH	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

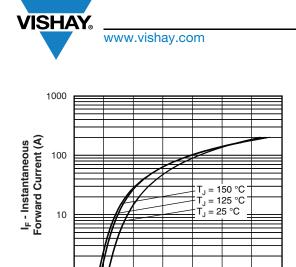
THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to 150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W	
Approximate weight			0.3	g	
Approximate weight			0.01	oz.	
Marking device		Case style DPAK	50WQ	10FNH	

Note

⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



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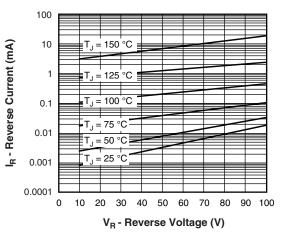


1

0

0.5

1.0



V_{FM} - Forward Voltage Drop (V) Fig. 1 - Maximum Forward Voltage Drop Characteristics

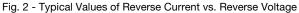
2.0

2.5

3.0

3.5

1.5



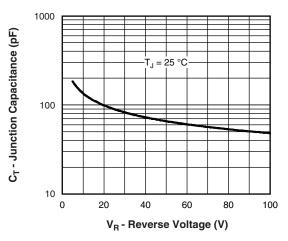


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

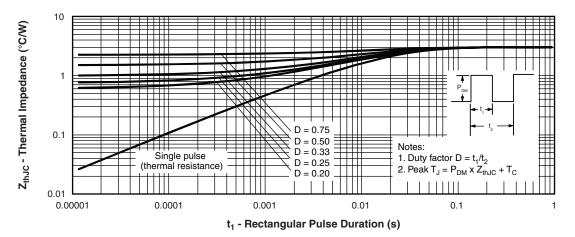


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

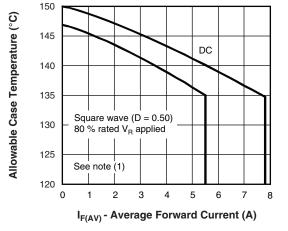
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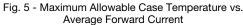
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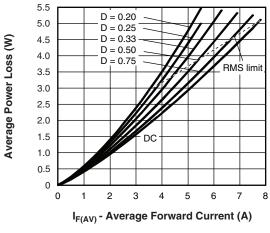


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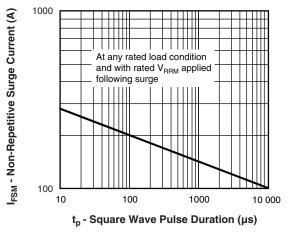


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

VS-50WQ10FNHM3

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ORDERING INFORMATION TABLE

Device code	VS-	50	w	Q	10	FN	TRL	н	М3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
	\bigcirc	\bigcirc	Ċ	\bigcirc	Ċ	Ċ	\bigcirc	C	Ċ
	1	- Visl	nay Sen	niconduo	ctors pro	oduct			
	2	- Cur	rent rati	ng (5.5 /	A)				
	3	- Pac	kage id	entifier:					
		W =	DPAK						
	4	- Sch	ottky "C)" series					
		- Voli	age rati	ng (10 =	= 100 V)				
		- FN	= TO-2	52AA (D	PAK)				
	7	- • N	one = T	ube					
		• TI	R = Tap	e and re	el				
		• TI	RL = Ta	pe and r	eel (left	oriente	d)		
	_			pe and		ht orien	ted)		
	드	- H=	AEC-Q	101 qua	alified				
	9			ntal digit					
		M3	= Halog	jen-free,	, RoHS-	complia	ant, and	termina	tions lea

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-50WQ10FNHM3	75	3000	Antistatic plastic tube				
VS-50WQ10FNTRHM3	2000	2000	13" diameter reel				
VS-50WQ10FNTRRHM3	3000	3000	13" diameter reel				
VS-50WQ10FNTRLHM3	3000	3000	13" diameter reel				

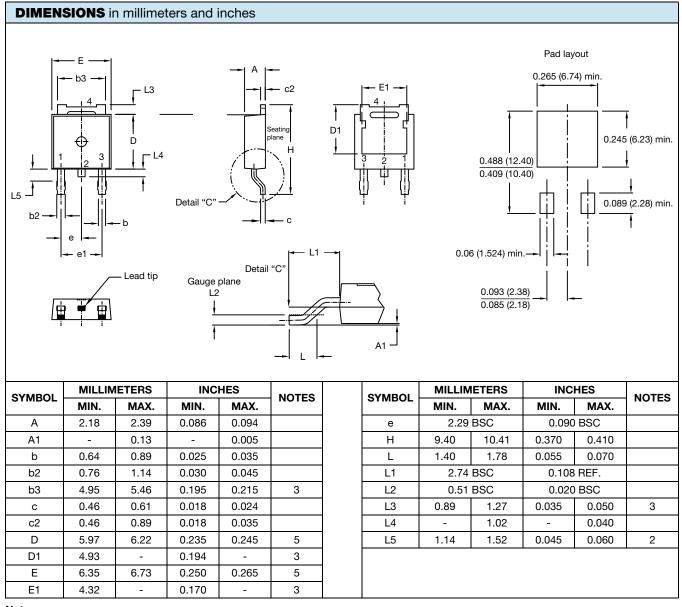
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				

Outline Dimensions



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DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA, except for D1 dimension



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